A ligning spins in antiferrom agnetic Im s using antiferrom agnets

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We have explored the possibility to orient spins in antiferrom agnetic thin Im s with low magnetocrystalline anisotropy via the exchange coupling to adjacent antiferrom agnetic Im s with high magnetocrystalline anisotropy. We have used M nO as a prototype for a system with negligible single-ion anisotropy. We were able to control its spin direction very electively by growing it as a Im on antiferrom agnetic C oo Im s with dilerent predeterm ined spin orientations. This result may pave the way for tailoring antiferrom agnets with low magnetocrystalline anistropy for applications in exchange bias systems. Very detailed inform ation concerning the exchange coupling and strain elects was obtained from the M n L_{2/3} soft x-ray absorption spectroscopy.

The study of the exchange bias phenomena in multilayered magnetic systems is a very active research eld in magnetism, not the least motivated by the high potential for applications in information technology. Various combinations of antiferrom agnetic (AFM) and ferrom agnetic (FM) thin lm materials have been fabricated and intensively investigated.^{1,2} There seems to be an agreement among the experimental and theoretical studies that the largest exchange biase ects can be found in systems containing AFM swith a high magnetocrystalline anisotropy, such as CoO. The simple underlying idea is that the anisotropy helps to x the spin orientation in the AFM while switching the magnetization in the FM.

O ur objective is to explore the possibilities to control and to pin the spin direction in AFM oxides having low m agnetocrystalline anisotropy, e.g. transition-m etal oxides with the $3d^3$, $3d^5$, or $3d^8$ ionic con gurations. If successful, this would help to extend the m aterials basis

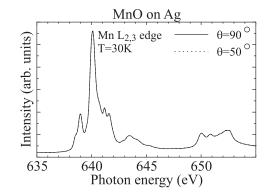


FIG.1: M n $L_{2;3}$ XAS spectra of a 50 m onolayer M n0 Im epitaxially grown in Ag(001). The spectra were taken with linearly polarized light, in which is the angle between the electric eld vector E and the [001] surface norm al. The sam – ple was measured at 30 K.

for the AFM sused in exchange bias system s. One could then consider thin $\ln s$ of not only N iO but also LaC rO₃, LaFeO₃, $-Fe_2O_3$, and $R_3Fe_5O_{12}$.³ At rst sight, our chances may seem bleak since a recent study on ultra In s reveals that the magnetic anisotropy rethin NiO sults from a detailed balance between the in uence of strain and thickness on the already very weak dipolar interactions in the AFM .4,5 A lso a very recent detailed report on M nO thin Im s grown on A g (100) substrates did not address the magnetic properties of the oxide lm, suggesting that it is di cult to detect m agnetic order in those Im s. Indeed, we ourselves have carried out at the ID 08 beam line of the ESRF in G renoble polarization dependent x-ray absorption spectroscopy (XAS) measurem ents at the M n $\rm L_{2,3}$ edges for a 50 m onolayer (M L) thin

In ofM nO epitaxially grown on Ag (100) and, as shown in Fig1, we could not observe any linear dichroic e ect which otherwise could have unam biguously indicated the presence of antiferrom agnetic order like there is for N iO on M gO $.^{7,8}$ This is most probably the result of having several di erently orientated anti-ferrom agnetic dom ains in the sample, canceling the net linear dichroic e ect.

On the other hand, the few studies available in the literature on combinations of AFM /AFM In s revealed that the interlayer exchange coupling can be very strong.^{9,10,11,12,13,14,15} W e took these ndings as starting point of our work. W e have used M nO as an idealm odel for an antiferrom agnetic system with negligible singleion anisotropy. For the antiferrom agnetic material with strong single-ion anisotropy we chose C oO. W e note that large magnetization loops shifts have been reported for M nO nanocrystallites deposited by reactive ion beam on C o m etal,¹⁶ which we took as support for our hypothesis that C oO /M nO interfaces may play an important role for the magnetic coupling. W e have grown M nO as a thin

In epitaxially on two di erent types of C oO single crystal Im s. In one C oO Im the spin direction is oriented perpendicular to the surface, and in the other parallel to the surface.¹⁷ U sing soft x-ray absorption spectroscopy at the M n L_{2;3} edges, we will show below that the spin direction of the M nO $\,$ Im strongly depends on the type of CoO $\,$ Im the M nO is grown on, and that it is dictated by the spin orientation of the CoO $\,$ Im and not by the strain or dipolar interactions in the M nO $\,$ Im . Interlayer exhange coupling is thus a very e ective manner to control spin directions and may be used for tailoring AFM s with low magnetocrystalline anisotropy for exchange bias applications.

The actual M nO /C oO systems studied are (14A)M nO / (10A)C oO / (100A)M nO /Ag (001) and (22A)MnO/(90A)CoO/Ag(001). The two samples were grown on a Ag(001) single crystal by molecular beam epitaxy (MBE), evaporating elemental Mn and Co from alum ina crucibles in a pure oxygen atm osphere of 10 7 to 10⁶ m bar. The base pressure of the MBE system is in the low 10¹⁰ m bar range. The thickness and epitaxial quality of the lms are monitored by re ection high energy electron di raction (RHEED) measurements. Both the CoO and MnO Im shad [001]/[001] epitaxial relationships with the underlying Ag(001) substrate. W ith the lattice constants of bulk Ag, CoO, and MnO being 4.09A, 4.26A, and 4.444A, respectively, we nd from x-ray di raction (XRD) and RHEED that the in-plane lattice constants in each Im are essentially given by the thickest layer which is almost bulk like. Compared to the bulk, the 10A CoO sandwiched by MnO is about 4% expanded in-plane (ak 4:424A), while the 90A CoO directly on Ag is slightly compressed in-plane (a_k 4:235A, a? 4:285A). The MnO is compressed in both samples, but much more so for the one on the 90A CoO lm. Details about the growth is given elsewhere.¹⁸ We have recently shown that the spin direction is oriented perpendicular to the surface in the CoO Im under tensile in-plane stress, and that it is parallel to the surface in the lm with the slightly com pressive in-plane stress.¹⁷

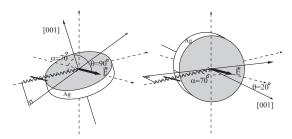


FIG. 2: Experim ental XAS geometry, with polarization of the light in the horizontal plane. is the angle between the electric eld vector E and the [001] surface norm al, and the tilt between the Poynting vector and the surface norm al.

The XAS m easurements were performed at the D ragon beam line of the NSRRC in Taiwan using in-situ MBE grown samples. The spectra were recorded using the totalelectron yield method in a chamber with a base pressure of 3 10 10 mbar. The photon energy resolution at

the M n $L_{2;3}$ edges (h 635 655 eV) was set at 0.2 eV, and the degree of linear polarization was 98%. The sample was tilted with respect to the incom ing beam, so that the Poynting vector of the light makes an angle of = 70 with respect to the [001] surface normal. To change the polarization, the sam ple was rotated around the Poynting vector axis as depicted in Fig. 2, so that , the angle between the electric eld vectorE and the [001] surface norm al, can be varied between 20 and 90. Thism easurem ent geom etry allows for an optical path of the incom ing beam which is independent of , guaranteeing a reliable comparison of the spectral line shapes as a function of . A M nO single crystal is measured simultaneously in a separate chamber to obtain a relative energy reference with an accuracy of better than 0.02 eV.

Fig. 3 shows the polarization dependent M n $L_{2,3}$ XAS spectra of the M nO /C oO sam ples with C oO spinorientation perpendicular (left panel) and parallel (right panel) to the surface, taken at tem peratures far below (top part) and far above (bottom part) the N celtem perature (T_N) of the M nO thin lm, which is about 130 K as we will show below. The spectra have been corrected for electron yield saturation e ects.¹⁹ The general line shape of the spectra shows the characteristic features of bulk M nO,²⁰ dem onstrating the good quality of our M nO

In s. Very striking in the spectra is the clear polarization dependence, which is the strongest at low tem peratures. It is important to note that below $T_{\rm N}$ the dichroism, i.e. the polarization dependence, of the two sam ples are opposite: for instance, the intensity of the peak A at h = 639 eV is higher for = 20 than for = 90 in M nO /CoO where the spin orientation of the CoO is out of plane, while it is sm aller in the other sam ple. Above $T_{\rm N}$, the dichroism alm ost vanishes. Nevertheless, sm all but clear and reproducible shifts in the spectra as a function of polarization can be seen: peak B at 640 eV has a shift of about 30 m eV for the M nO grown on top of the 90A CoO $\,$ Im .

In order to resolve the origin of the dichroism in the spectra, we have investigated the temperature dependence in more detail. The measurements were done by taking the spectra starting from the lowest temperature (T = 67K or T = 77K) towards higher temperatures and after the highest temperature was reached (T = 200K or T = 400K) we returned to low temperatures and acquired new spectra in between the previously measured temperatures. Fig. 4 depicts the polarization contrast of peak A, de ned as the di erence divided by the sum of the peak height in the spectra taken with the = 20 and = 90 polarizations. In going from low to high temperatures, one can see a signi cant temperature dependence for both samples (with opposite signs), which attens o at about 130K, identi ed as the T_N of these M n0 thin

In s. We therefore infer that at low temperatures the strong dichroic signal is caused by the presence of m agnetic ordering. Important is to note that the opposite sign in the dichroism for the two samples implies that

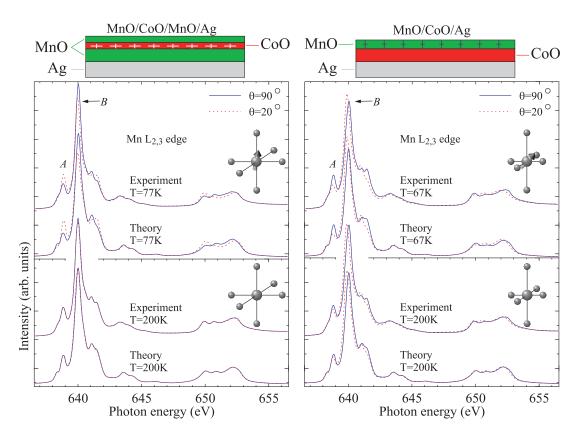


FIG. 3: (color online) Experimental and calculated M n $L_{2;3}$ XAS spectra of M nO in (left panel) (14A)M nO / (10A)C oO / (100A)M nO / Ag(001) and (right panel) (22A)M nO / (90A)C oO / Ag(001) for = 20 and = 90. Spectra below (T = 77K left, T = 67K right panel) and above (T = 200K) the T_N of the M nO lm are shown in the top and bottom parts, respectively.

the orientation of the m agnetic m om ents is quite di erent. Here we recall that M nO lm s grown on Ag without CoO do not show any dichroism down to the lowest tem peratures, indicating the crucial role of the CoO in orienting the m agnetic m om ents of the M nO .

To understand the Mn L_{2;3} spectra quantitatively, we perform ed calculations for the atom ic-like $2p^63d^5$! 2p⁵3d⁶ transitions using a sim ilarm ethod as described by Kuiperetal.²¹ and Aldersetal,⁸ but now in a D_{4h} point group symmetry and including covalency. The method uses a M nO 6 cluster which includes the full atom ic m ultiplet theory and the locale ects of the solid 20,23 It accounts for the intra-atom ic 3d-3d and 2p-3d C oulom b and exchange interactions, the atom ic 2p and 3d spin-orbit couplings, the O 2p - M n 3d hybridization, local crystal eld param eters 10D q, D s, and D t, and a Brillouintype tem perature dependent exchange eld which acts on spins only and vanishes at T_N . As in earlier works, 8,17 an average has been m ade over all possible equivalent m agnetic dom ains in the local D_{4h} crystal- eld point group, canceling out the e ects of an isotropic magnetic linear dichroism.²² The calculations were carried out using the XTLS 8.0 program .²³

The results of the calculations are shown in Fig. 3. We used the parameters already known for bulk M nO 23,24 and tuned only the parameters for D s, D t, and the di-

rection of the exchange eld. For the M nO sandwiching the 10A CoO we nd an excellent simulation of the experim ental spectra for D = 9.3 meV, D = 2.6 meV, and an exchange eld parallel to the [112] direction. For the M nO overlaying the 90A CoO we obtained the best t for Ds = 48.6 meV, Dt = 11.1 meV, and an exchange eld along the [211] direction. These two sets of param eters reproduce the spectra at all tem peratures extremely well. This is also demonstrated in Fig. 4, showing the excellent agreem ent between the calculated and measured temperature dependence of the dichroism in peak A. Most important is obviously the inform ation concerning the spin direction that can be extracted from these simulations. Earlier results have shown that in-plane tensile strained CoO layers (c/a<1) have their spin orientation parallel with the [001] direction while slightly compressed CoO/Aq(001) layers (c/a>1) have spin orientation perpendicular with the [001] direction.¹⁷ We thus nd that the magnetic moments in the MnO are oriented towards the surface norm alwhen it is grown on In which has the spin direction perpendicular the C oO to the surface, and that it is lying towards the surface when MnO is grown on the CoO lm which has the parallel alignment. In other words, it seems that bulk-like M nO domains are stabilized that follow the CoO spin-

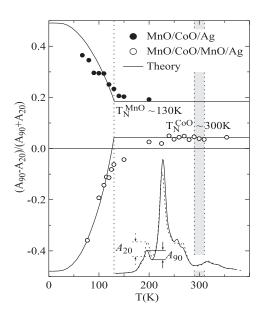


FIG.4: Tem perature dependence of the polarization contrast in the M n $\rm L_{2;3}$ spectra, de ned as the di erence divided by the sum of the height of peak A at h = 639 eV, taken with = 20 and = 90 polarizations. Filled and empty circles are the experim ental data. The solid lines are the theoretical simulations. The shaded area represents the $T_{\rm N}$ of the CoO layers under the M nO $\,$ lm .

direction as much as possible.

In order to nd out whether the spin direction in the M nO thin lm s is determined by the exchange coupling with the CoO, or whether it is given by strain and dipole interactions in the lm s as found for N iO thin lm s on non-magnetic substrates,^{4,5} we now have to look more closely into the tetragonal crystal elds in the M nO lm s. The values for the tetragonal crystal elds in the M nO lm s. The values for the tetragonal crystal elds in the excellent sim – ulations as plotted in Fig. 3, can actually be extracted alm ost directly from the high-tem perature spectra, where the magnetic order has vanished and does not contribute anym ore to the polarization dependence.

The top panels of Fig. 5 show a close-up of the spectra taken at 200K , i.e. above $T_{\rm N}$. O ne can now observe the small but clear and reproducible shifts in the spectra as a function of polarization: the shift in peak A is denoted by $_{\rm A}$ and in peak B by $_{\rm B}$. In order to understand intuitively the origin of these shifts, we will start to describe the energetics of the high spin M n^{2+} (3d⁵) ion in a one-electron-like picture. In O $_{\rm h}\,$ sym m etry the atom ic 3d levels are split into 3 t_{2g} and 2 e_g orbitals, all containing a spin-up electron. The L_3 edge of M n^{2+} should then consist of two peaks: in exciting an electron from the 2p core level to the 3d, one can add an extra spin-down electron either to the lower lying t_{2q} or the higher lying eq shell, producing peaks A and B, respectively. In the presence of a tetragonal distortion, both the t_{2q} and e_q levels will be split, resulting in a polarization dependent shifts $_{\rm A}$ and $_{\rm B}$, analogous as found for N iO 25

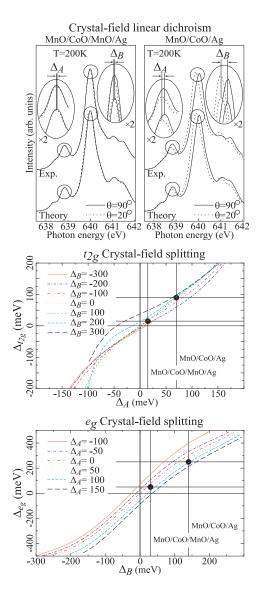


FIG.5: (color online) (top panel) C lose-up of the experim ental and calculated M n L₃ XAS spectra at 200K, i.e. above T_N of (left) (14A)M nO / (10A)C oO / (100A)M nO / A g (001) and (right) (22A)M nO / (90A)C oO / A g (001); A and B are the polarization dependent shifts in peaks A and B, respectively; (m iddle and bottom panels) Relationship between f A, B g and the tetragonal f e_q , t_{2q} g splittings.

D ue to the intra-atom ic 2p-3d and 3d-3d electron correlation e ects, the relationship between the shifts in the spectra and the crystal eld splittings become non-linear. Using the cluster model we are able to calculate this relationship for a M n²⁺ 3d⁵ system and the results are plotted in Fig. 5. Using this map, we nd for the M nO sandwiching the 10A CoO that $t_{2g} = 15$ m eV and $e_g = 50$ m eV, and for the M nO overlaying the 90A CoO that $t_{2g} = 90$ m eV and $e_g = 250$ m eV (D s= $(e_g + t_{2g})/7$, D t= $(3e_g - 4t_{2g})/35$). The crystal eld splittings for the second sample are much larger than for the rst sample. This is fully consistent with

our structural data which indicate that in the second sam ple M nO experiences a much stronger compressive in-plane strain. It is important to recognize that the crystal eld splittings for the two sam ples have the sam e sign, i.e. that both M nO Im s are compressed in plane. This implies that strain togetherw ith the dipolar interactions cannot explain the quite di erent spin-orientations of the two M nO system s. We conclude that the magnetic anisotropy mechanism present in, for instance, N io thin Im s on non-magnetic substrates,^{4,5} is overruled by the stronger interlayer exchange coupling^{9,10,11,12,13,14,15} between the CoO and M nO layers.

The $T_{\rm N}$ for these thin M nO layers is found to be at about 130 K. It is surprising that the N eel temperature is not reduced as compared to the bulk value of 121 K, 26 since generally one would expect this to happen with decreasing thickness as was observed for N iO on M gO 8 The origin for such a surprising behavior is not clear at this moment. It is possible that the in-plane compressive stress causes an increase in the M n 3d - O 2p hybridization, which in turn could produce an increase of the superexchange interaction strength^3 and thus also of $T_{\rm N}$. A nother, more exciting, possibility emerges from the recent experimental

and theoretical work on AFM /AFM multilayers such as FeF₂/CoF₂ and CoO/NiO $.^{9,10,11,12,13,14,15}$ Experiments have revealed that multilayers could even have a single magnetic ordering transition temperature lying in between the two $T_{\rm N}$ s of the constituent materials. The phenomenon has been ascribed to the very strong interlayer exchange coupling.

In conclusion, we have shown that it is possible to control the spin direction in M nO very e ectively by growing them as thin ln s on antiferrom agnetic CoO ln s with di erent predeterm ined spin orientations. Using detailed M n $L_{2,3}$ soft x-ray absorption spectroscopy, we are also able to show that it is not strain but interlayer exchange coupling which plays a decisive role herein. This result may pave the way for tailoring antiferrom agnets with low magnetocrystalline anistropy for applications in exchange bias.

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